## A nom alous coupling betw een topologicaldefects and curvature

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W e investigate a counterintuitive geom etric interaction between defects and curvature in thin layers of super uids, superconductors and liquid crystals deposited on curved surfaces. Each defect feels a geom etric potential whose functional form is determ ined only by the shape of the surface, but whose sign and strength depend on the transform ation properties of the order param eter. For super uids and superconductors, the strength of this interaction is proportional to the square of the charge and causes all defects to be repelled (attracted) by regions of positive (negative) G aussian curvature. For liquid crystals in the one elastic constant approxim ation, charges between 0 and 4 are attracted by regions of positive curvature w hile all other charges are repelled.

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The physics of topological defects on curved surfaces plays an increasingly signi cant role in the engineering of devices based on coated interfaces.  $[1, 2, 3]$ . D efects also a ect the m echanical properties of some biological system s, such as spherical viruses, whose shape is dependent on the presence of disclinations in their protein shell [\[4](#page-3-3)]. Furtherm ore, the e ects induced by a curved substrate on the distribution of defects are not fully understood even in well studied system s such as thin lm s of super uid helium and type II superconductors. In this paper, we study simple continuum generalizations of the plane XY m odel to frozen surfaces of varying curvature to gain a broad understanding ofthe interaction between topologicaldefects and curvature.

T heX Y m odelisa sim plesetting in w hich particle-like objects em erge from a m ore fundam entaltheory. The basic degree of freedom is an angle-valued function on the plane w hose values vary from 0 to 2. These angles could represent the orientations of interacting arrow s. The interaction, w hich tends to align neighboring arrows, results from the continuum free energy F given by

<span id="page-0-0"></span> $\overline{7}$ 

$$
F = \frac{K}{2}^{2} d^{2}u (r (u))^{2} ; \qquad (1)
$$

where the set of coordinates  $u = (x; y)$  label points on the plane. D espite its simplicity, thism odel captures the m ain properties of vortices in layers of super uid  $4$ H e or thin superconducting  $\ln s$  when the eld (u) is identi ed w ith the phase of the collective wave function. In addition, the elastic energy of  $Eq.(1)$  $Eq.(1)$  correctly describes liquid crystalline phases for which the bond angle,  $(u)$ , has periodicity  $\frac{2}{p}$  with p 3. For a solution of nem atigens  $(p = 2)$  and tilted m olecules in a a Langmuir lm  $(p = 1)$  two dierent elastic constants are necessary to account for bend and splay deform ations [\[5\]](#page-3-4), but these are renorm alized to the sam e value at nite tem pera-tures [\[6](#page-3-5)]. Besides its experimental signi cance, the XY m odel is the comerstone of our conceptual understanding of topological defects, singular con gurations of the eld (u ).

Like particles, defects have charges and a characteristic C oulom b-like interaction. T he charge q, a m ultiple of

 $\frac{2}{p}$ , can be de ned by the amount increases along a path enclosing the defect's core. T he force between two defects located at positions  $u_i$  and  $u_j$  is determ ined by the energy  $E_{int}$  stored in the eld:

$$
E_{int} = K q_i q_j U (u_i; u_j); \qquad (2)
$$

where the inter-particle potential U  $(u_i; u_j)$  is proportionalto the logarithm ofthe distance in the plane.

On a at surface, thin layers of super uids, superconductorsand liquid crystalscan allbe analyzed w ithin the fram ework of Eq.[\(1\)](#page-0-0) [\[7\]](#page-3-6). H owever, there is a crucial difference between, say, the phase of the super uid order param eter and the angle that describes the local orientation of liquid crystalm olecules. The form er transform s like a scalar since the quantum m echanical phase does not change w hen the system is rotated, w hile the latter represents a vector aligned to the localdirection of the m olecules. Thus, a comm on boundary condition for a liquid crystalis for the director to be tangent to the boundary of the substrate. By contrast, no such constraint exists for a lm of  $4H$  e because its wave function is dened in a dierent space from the one in w hich the super uid is con ned. This distinction is crucial on a curved surface. In the ground state of a  $4$ He  $\,$  m, the phase (u) is constant throughout the surface and the corresponding energy vanishes. The free energy  $F_s$  to be m in in ized is a scalar generalization of  $Eq.(1)$  $Eq.(1)$ :

<span id="page-0-1"></span>
$$
F_s = \frac{K}{2} \frac{Z}{d^2 u^2 \overline{g} g} \quad (a \quad u) (8 \quad (u) : \qquad (3)
$$

H ere the set of coordinates  $u = (u_1; u_2)$  label points on the surface while  $\frac{p}{q}$  is the determ inant of the m etric  $tensor g$  . On the other hand, a constant bond angle

(u) is not the ground state of the liquid crystal because it is m easured w ith respect to an arbitrary basis vector E (u) with =  $1;2$ . Indeed, it is not possible to m ake the directions of the m olecules parallel everyw here on a curved space; the lowest energy state is attained by optim ally distributing the unavoidable bend and splay of the vectors over the w hole surface. T he free energy functional  $F_v$  to be m in in ized is a vector generalization

<span id="page-1-0"></span> $ofEq.(1) [8]:$ 

$$
F_v = \frac{K}{2} \frac{Z}{d^2 u^2} \frac{d^2 u^2}{dy^2} \frac{d^2 u}{dx^2} \frac{
$$

(u), the connection, compensates for the row here tation of the 2D basis vectors  $E$  (u) in the direction of u. Since the curlof the connection is equal to the G aussian curvature, the integrand in  $Eq.(4)$  cannot bem ade to vanish on a surface with non-zero curvature. The connec $t<sub>ion</sub>$  $(u)$  is a non-conservative eld and hence cannot be equal to  $\ell$  . A s the substrate becomes m ore curved, the energy cost of this geometric frustration can be lowered by generating defects in the ground state even in the absence of topological constraints [9, 10].

In this letter, we demonstrate that topological defects in super uids and superconductors interact with the curvature in a way that is radically di erent from what happens in the case of liquid crystal order. In both cases, the electrostatic interaction between the defects U  $(u_i, u_i)$  is given by the G reen's function of the covariant Laplacian and its functional form depends on the shape of the surface under consideration [18]. However, the interaction w ith the G aussian curvature di ers in the two cases and it will be explicitly derived from the transform ation properties of the order parameter. For thin layers of super-

uids and superconductors, we nd that the geometric interaction  $E_{\text{curv}}^s$  (u<sub>i</sub>) is given by:

<span id="page-1-1"></span>
$$
E_{\text{curv}}^{s} \left( u_{i} \right) = \frac{K}{4} q_{i}^{2} V \left( u_{i} \right) ; \qquad (5)
$$

where  $u_i$  and  $q_i$  are respectively the position and topological charge of the defect. The geometric potential V (u) satis es a covariant version of Poisson's equation where the negative of the G aussian curvature  $G(u)$  plays the role of the charge density:

D D V (u) = G (u) : 
$$
(6)
$$

For surfaces with azimuthal symmetry one can derive an explicit expression for  $V(u)$  by using a two dimensional anabgue of G auss' law [9]. The m ain consequence of Eq.  $(5)$  is that topological defects in super uid and superconducting In s are repelled (attracted) by positive (negative) G aussian curvature irrespective of their sign.

In the case of liquid crystal order, the energy  $E_{curv}^{v}(u_i)$ corresponding to the defect-curvature interaction contains the same function  $V(u)$  as in Eq.(5) but with an unusual dependence on the charge of the defect:

<span id="page-1-2"></span>
$$
E_{\text{curv}}^{\nu} (u_i) = K q_i \quad 1 \quad \frac{q_i}{4} \quad V (u_i) \tag{7}
$$

The interpretation of V (u) as a geom etric potential and the linear dependence on the charge of the defect in the

rst term of  $Eq.(7)$  are consistent with the general belief that defects interact logarithm ically with the Gaussian curvature, as electrostatic particles would with a background charge distribution. However,  $E_{\text{curv}}^{V}$  (u<sub>i</sub>) does not



<span id="page-1-3"></span>FIG. 1: A corrugated substrate and its downward projection on a at plane. The shaded strip surrounding P is more stretched than the one surrounding Q despite their projections onto the plane having the same area. The energy stored in the eld will be lower if the core of the defect is located at  $O$  rather than  $P$ .

grow linearly with the charge of the defect, as expected from the electrostatic analogy. Instead, the geom etric interaction peaks for a defect of charge 2 and eventually becom es repulsive for q greater than the critical charge  $q = 4$ .

The quadratic coupling in Equations (5) and (7) has an intuitive explanation in the case of azimuthally sym  $$ m etric surfaces. Consider a very thin super uid In deposited on the surface illustrated in Fig. 1 with a vortex of charge q placed on top of the bump. In order to calculate the energy stored in the eld, we only need the gradient of the super uid phase in the direction of the azimuthal angle . The super uid phase (u) changes uniform ly by q along a circum ference of length 2 r centered on the defect. Inspection of Eq.(3) reveals that the energy density of the eld in the shaded strip at distance r is proportional to  $\frac{q}{r}^2$ , where r is the distance to the singularity measured in the plane of projection (see Fig. 1). By vertically stretching the surface, the am ount of area in the shaded strip is increased with respect to its projection on the plane, while the energy density is unchanged. As a result, the total energy stored in the eld is greater when a vortex sits on top of a bum py surface than when the same vortex is located at the center of a at disk of the same area. Hence, it is energetically favorable for the vortex to m igrate to the at portions of the surface. In this case, the vortex is far away from the bump so that the total energy stored in the eld does not dier much from the at plane result [11]. In the case of less symmetric surfaces, the resulting geometric interaction will depend on the shape of the entire surface as embedded in the metric tensor.

The physical origin of the linear coupling between defects and curvature in Eq.(7) is well known and is illustrated in Fig. 2 for a disclination of charge 2 centered on a bump. As the curvature of the bump is increased,



<span id="page-2-0"></span>FIG .2: D isclinations of charge 2 located on top of bum ps w ith dierent aspect ratios. The am ount of splay in the liquid crystaldirector on the taller bum p is reduced and hence the energy density is lower.

the bend or splay of the director of the liquid crystal decreases and hence the energy stored in the vector eld is reduced. A s a result, this linear coupling causes positively (negatively) charged defects to be attracted by positive (negative) G aussian curvature [\[12\]](#page-3-11). H owever, this m echanism com petes w ith the repulsive geom etric interaction illustrated in Fig. [1](#page-1-3) that is at work also in the case of liquid crystal order.

The critical value  $q_c = 4$ , where the single defect potential  $E_{\text{curv}}^{\text{v}}(u_i)$  changes sign, can be determ ined from sim ple geom etricalargum ents. C onsider an isolated defect of charge q on a hem ispherical cup placed on a at plane. On account of azim uthalsym m etry, the force acting on the defect depends only on the net G aussian curvature enclosed by the circle on w hich it is placed, see Fig. [3a](#page-2-1). This interaction is unchanged if we deform the outer region of the plane and eventually com pactify it to form a sphere as illustrated in Fig[. 3b](#page-2-1). In order to satisfy topo-logical constraints [\[19\]](#page-4-1), we still need to place a shadow defect of charge  $(4 \text{ q})$  at the south pole (the only position outside the circle that does not destroy the azim uthal sym m etry of the initial problem ). The curvature-defect interaction on the hem isphere is thus reduced to the well know n defect-defect interaction on the sphere [\[13\]](#page-4-2). T he latter is proportional to  $q(4 - q)$  and so is the curvaturedefect interaction on the deform ed plane of  $F$  ig. [3a](#page-2-1), in agreem ent with  $Eq.(7)$  $Eq.(7)$ . This provides evidence that a defect of charge greater than 4 w ill be repelled from regions of positive curvature in the case of liquid crystal order.

The coupling between curvature and defects in helium and superconducting Im s can be investigated quantitatively by the method of conform alm apping which is often adopted in electrom agnetism and 
uid m echanics to sim plify the boundary of complicated planar regions. We use conform alm appings to relate the complex task of nding the eld energy on an arbitrarily deformed target surface to an equivalent problem on a hom ogeneous reference surface (see Fig. [4\)](#page-3-12). A conform alm apping has two equivalent de ning properties: angles m ap to equal angles, and very sm all quresm ap to qures of nearly the sam e shape. O ne can always nd a conform alm apping



<span id="page-2-1"></span>FIG . 3: (a) An isolated disclination on a deform ed plane feels a force that depends only on the enclosed G aussian curvature. (b) The deform ed plane is compactied to the sphere by placing a shadow defect at the south pole.

from the target to the reference surface [\[14\]](#page-4-3) such that

<span id="page-2-2"></span>
$$
g_{\rm T} = e^{2! \; (\mathrm{u})} g_{\rm R} \qquad (8)
$$

where  $q_T$  and  $q_R$  are the m etric tensors on the target and reference surfaces respectively. T he scaling factor of lengths  $e^{-\frac{1}{2}(u)}$  varies with the position u on the target surface, so that larger gures are inhom ogeneously distorted.

In the present treatm ent, we concentrate on deform ed spheres and corrugated planes. In this case,  $#$  is convenient to choose the reference surfaces to be undeform ed and of the sam e topology as the target spaces. As a result of the conform altransform ation, defects on the target surface are m apped onto a set of\im age defects" on the reference surface. The crucial property of the scalar free energy  $F_s$  is its invariance under the rescaling of the m etric described in Eq[.\(8\)](#page-2-2)  $[20]$ . H owever, the conform al sym m etry of  $F_s$  is broken upon introducing a short distance cuto a that is necessary to prevent the energy from diverging in the core of the defect. Because of the varying scaling factor, the constant physical core radius a is stretched or contracted when projected on the reference space by an am ount dependent on the position of the defect  $(\sec F \text{ is } 4)$  $(\sec F \text{ is } 4)$ . The radius of the im age of the  $\mathrm{i}^\mathrm{th}$  core is

$$
a_i = e^{-\frac{1}{2} (u_i)} a
$$
 (9)

<span id="page-2-3"></span>It is this conform alanom aly that is responsible for generating the geom etric interaction in Eq. $(5)$ . In fact, the energy of the defects in the target space  $E_T$  is equal to the energy of a con quration of defects (on the reference surface) whose core radii are position-dependent. This problem can be further transform ed into the simpler task of nding the energy  $E_R$  for a set of interacting defects w ith constant core radius a plus an e ective geom etric potential that accounts for the variation of the core size w ith position. This geom etric potential can be derived w ith the aid of Fig. [4.](#page-3-12) If  $a_i$  is sm aller (larger) than  $a_i$ , the energies stored in the annular regions indicated in Fig. 4 need to be added (subtracted) from  $E_R$  to obtain  $E_T$ . To calculate this extra energy, we introduce a set of



<span id="page-3-12"></span>FIG . 4: C on form alm apping of the target surface T onto the reference space R . The continuous disks on both surfaces represent the \physical" cores of constant radius a. The dashed lines represent the position dependent in ages on R of the defect cores on T. N ote that the energy stored in the annuli com prised by the dashed and continuous lines in R needs to be added or subtracted to  $E_R$  to obtain  $E_T$ .

polar coordinates (r, ) centered on the  $\rm i^{\rm th}$  defect. Near the defect of charge  $q_i$ , the phase is given by

$$
\frac{q_i}{2} \qquad (10)
$$

<span id="page-3-13"></span>and the energy density is  $\frac{K\;q_{1}^{2}}{8\;2\;r^{2}}$  . U pon integrating it over the i<sup>th</sup> annulus and substituting  $a_i$  from Eq[.\(9\)](#page-2-3), we obtain

$$
E_T \t E_R = K \frac{\dot{X}^d}{4} \t (u_i) ; \t (11)
$$

where N  $_d$  is the num ber of defects. The energy  $E_R$  contains only the defect-defect interactions since any potential felt by a single defect would have to be constant because all points are equivalent on the reference surface (undeform ed sphere or plane). T he anom alous coupling between defects and curvature introduced by  $!$  (u) is controlled by the overall shape of the surface and does not depend on the m icroscopic physics that determ ines the core size because the length a drops out in Eq[.\(11\)](#page-3-13). For a deform ed surface with the topology of the plane, the Laplacian of  $\;$  ! (u) is equal to the G aussian curvature [\[21\]](#page-4-5). H ence,  $\cdot$  (u<sub>i</sub>) is the geom etric potential V (u<sub>i</sub>) in-troduced in Eq[.\(5\)](#page-1-1) [\[9](#page-3-8)]. In the case of liquid crystalorder, the contribution of the anom aly is simply added to the

term linear in q arising from cross term s in Eq[.\(4\)](#page-1-0) [\[9\]](#page-3-8). The resulting expression for the coupling of each defect to the curvature of the space is given in  $Eq.(7)$  $Eq.(7)$ .

Position-dependent core energies can also result from abandoning the phase-only approximation to the super uid energy. However, the amplitude of the wavefunction varies appreciably from its equilibrium value only inside the defect cores. A ny resulting change in the core energy ofa defect would be proportionalto the local curvature. This contribution varies inversely as the area of the surface and can be m ade arbitrarily sm all by rescaling the surface, unlike the geom etric potential in Eq[.\(11\)](#page-3-13). Sim ilarly, higher order term sin a soft-spin Landau expansion would be m ost im portant near the defect cores and hence negligible in the lim it of large surfaces  $[15]$ .

Experim ents that test our predictions can be realized by coating a bump with a thin layer of super uid helium and rotating it around its axis of symmetry so that a single vortex form s [\[16\]](#page-4-7). The competition between the (repulsive) geom etric interaction and the con ning parabolic potential (generated by the rotation) would cause the equilibrium position of the vortex to shift from the center of the bum p if its height exceeds a critical value. T he vortex line could be detected by trapping of electrons on its core [\[17](#page-4-8)]. O ther experim ents m ay detect an inhom ogeneous distribution of therm ally induced defects resulting from the combined eect of the anom alous coupling and the dependence of their C oulom b-like interaction on the varying curvature.

W e have dem onstrated that the interaction between defects and curvature in 2D X Y -like m odels depends crucially on the nature of the underlying order param eter and we have show n how to explicitly derive the resulting geom etric force from the shape of the surface.

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at space.T his com plication results in an im plicit coupling of a set of interacting defects to the geom etry of the substrate.
- <span id="page-4-1"></span>[19] T he Poincare-H opf theorem states that the sum of the charges of the defects for a vector eld is equal to the integrated G aussian curvature which is in turn equal to 4 (1 g),w hereg isthe genusofthe surface.Fora scalar eld the sum of the charges is zero.
- <span id="page-4-4"></span>[20] W hen  $g_T$  is substituted in Eq[.\(3\)](#page-0-1) the conform al factor cancels out and  $\frac{p}{g_T} \frac{q_T}{g_T} = \frac{p}{g_R} \frac{q_T}{g_R}$ .
- <span id="page-4-5"></span>[21] See R ef. [\[8\]](#page-3-7) pp. 178-180 and references therein. The details of the analysis valid for deform ed spheres w ill be presented elsew here [\[15](#page-4-6)].